

# **CONDUCTION COOLED (CS) DIODE LASER BARS**



nLIGHT's industry recognized conduction cooled (CS) diode laser package features a 30% fillfactor bar that is rated at 60 W on an industry standard conduction cooled CS package. By combining nLIGHT's proprietary nXLT™ (eXtended Life Technology) laser chips with AuSn solder on an expansion-matched sub-mount, nLIGHT is able to offer a significant increase in power and brightness while increasing lifetime for CW, pulsed, and high temperature applications.

The standard packaging footprint allows these bars to easily integrate into your product. nLIGHT's proprietary fast-axis lensing capability can further improve the brightness of these conduction cooled bars. This in-house lensing capability makes applications in solid-state laser pumping and materials processing integration into more complex optical systems easier.

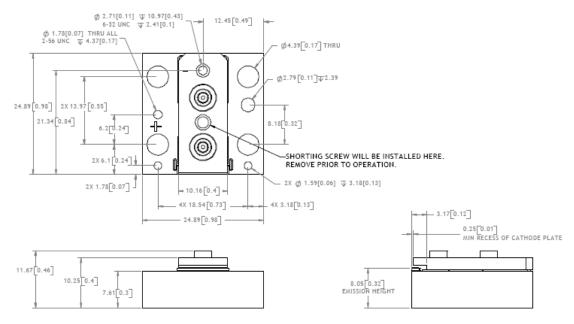
# **Applications**

- Solid-state laser pumping
- Materials processing
- Medical therapeutics
- Graphic arts

## **Features**

- High brightness
- Superior reliability
- Low bar smile
- Superior near field uniformity
- High polarization purity
- High temperature operation

## Package dimensions





### HIGH-POWER SEMICONDUCTOR LASERS AND FIBERS

## Typical device specification

CW output power W Center wavelength tolerance nm	90 - 830 60 ± 3 150 x 1 19 150
CW output power W Center wavelength tolerance nm Emitter area µm Number of emitters #	60 ± 3 150 x 1 19 150
Center wavelength tolerance nm Emitter area	±3 150 x 1 19 150
Emitter area	150 x 1 19 150
Number of emitters #	19 150
	150
Emitter size	
Liniter 6/26	F00
Emitter spacing µm	500
Spectral width (FWHM) nm	< 3
Slope efficiency W / A	> 1.1
Polarization TM or TE	TE
Fast-axis divergence Degrees	36°
Slow-axis divergence Degrees	10°
Wavelength temperature coefficient <sup>1</sup> nm 0	).28 / °C
Electrical	
Total conversion efficiency %	52
Threshold current A	10
Operating current A	60
Operating voltage V	< 1.9
Series resistance $\Omega$	0.002
Mechanical	
Storage temperature range <sup>3</sup> °C -2	20 to +80
Thermal	
Thermal resistance <sup>2</sup> °C / W	0.75
Operating temperature <sup>3</sup> °C -2	20 to 30

<sup>&</sup>lt;sup>1</sup> The wavelength temperature coefficient is the wavelength shift per °C change at the diode junction.

#### **CFR Regulation**

These components do not comply with the federal regulation (Title 21 CFR, Chapter 1, Subchapter J) as administered by the Center for Device and radiological Health. Purchaser acknowledges that their products must comply with these regulations before they can be sold to an end-user.



#### Notice

nLIGHT continually improves its products to provide our customers with outstanding quality and reliability. nLIGHT may make changes to specifications and product descriptions at any time, without notice. In addition, nLIGHT offers a limited warranty to ensure customer satisfaction. For complete details, please contact your nLIGHT sales representative.

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<sup>&</sup>lt;sup>2</sup> Thermal resistance is the diode junction temperature shift per incremental Watt of heat load.

<sup>&</sup>lt;sup>3</sup> A non-condensing environment is required for storage and operation below ambient dew point.